

#### **DATA SHEET**

# Silicon Schottky Barrier Diode Bondable Chips and Beam Leads

### **Applications**

- Detectors
- Mixers

#### **Features**

- Available in both P-type and N-type low barrier designs
- Low 1/f noise
- Large bond pad chip design
- Planar passivated beam-lead and chip construction



Skyworks Green<sup>TM</sup> products are compliant with all applicable legislation and are halogen-free. For additional information, refer to *Skyworks Definition of Green*<sup>TM</sup>, document number SQ04-0074.



Skyworks beam-lead and chip Schottky barrier detector diodes are designed for applications through 40 GHz in the Ka band. They are made by the deposition of a suitable barrier metal on an epitaxial silicon substrate to form the junction. The process and choice of materials result in low series resistance along with a narrow spread of capacitance values for close impedance control. P-type silicon is used to obtain superior 1/f noise characteristics. N-type silicon is also available.

Beam-lead and chip diodes can be mounted on special customer substrates.

Unmounted beam-lead diodes are especially well suited for use in microwave integrated circuit (MIC) applications. Mounted beam-lead diodes can be easily used in MIC, stripline, or other such circuitry.

These "universal chips" are designed for a high degree of device reliability in both commercial and industrial uses. The offset bond pad assures that no mechanical damage occurs at the junction during the wire bonding. Additionally, the 4 mil bond pad eliminates performance variation due to bonding, improves efficiency during manual operations, and is ideal for automated assembly.



The choice of N- and P-type silicon allows the designer to optimize the silicon material for the intended application:

- Doppler mixers and high-sensitivity detectors benefit from using the low noise characteristics of the P-type silicon.
- Low conversion loss mixers and biased detectors can be designed using standard N-type material.

### **Applications**

These diodes are categorized by tangential signal sensitivity (TSS) for detector applications in four frequency ranges: S, X, Ku, and Ka bands. However, they can also be used as modulators, high-speed switches, and low-power limiters.

TSS is a parameter that describes a diode's detector sensitivity. It is defined as the amount of signal power, below a one-milliwatt reference level, required to produce an output pulse with an amplitude sufficient to raise the noise fluctuations by an amount equal to the average noise level. TSS is approximately 4 dB above the minimum detectable signal.

The P-type Schottky diodes in this Data Sheet are optimized for low noise in the 1/f region. They require a small forward bias (to reduce video resistance) if efficient operation is required. The bias not only increases sensitivity but also reduces parameter variation due to temperature change. Video impedance is a direct function of bias and follows the 26/I (mA) relationship. This is important to pulse fidelity since the video impedance together with the detector output capacitance affects the effective amplifier bandwidth.

Bias does, however, increase typical noise, particularly in the 1/f region. Therefore, it should be kept as low as possible (typically 5 to 50  $\mu$ A).

Additional bonding and handling methods are contained in the Skyworks Application Notes, *Waffle Pack Chip Carrier Handling/Opening Procedure* (document #200146) and *Diode Chips, Beam-Lead Diodes, Capacitors: Bonding Methods and Packaging* (document #200532).

### **Electrical and Mechanical Specifications**

Electrical and physical specifications for the silicon Schottky barrier diodes are provided in Tables 1 through 3. SPICE model parameters are defined in Table 4. Typical performance characteristics are shown in Figures 1 through 4. Typical video detector circuits are shown in Figure 5.

Table 1. DDB2503/04, DDB2265, CDB7619/20, CDF7621/23, CME7660, CDE7618 and CDP7624 Diode Series Absolute Maximum Ratings<sup>1</sup>

Parameter	Symbol	Minimum	Maximum	Units
Reverse voltage	VR		2	V
Forward current	lF		100	mA
RF input power @ TA = 25 °C	Po		75	mW
Storage temperature	Тѕтс	-60	+200	°C
Operating temperature	TA	-55	+150	°C
Electrostatic discharge: Human Body Model (HBM), Class )	ESD		<250	V

<sup>1</sup> Exposure to maximum rating conditions for extended periods may reduce device reliability. There is no damage to device with only one parameter set at the limit and all other parameters set at or below their nominal value. Exceeding any of the limits listed here may result in permanent damage to the device.

ESD HANDLING: Industry-standard ESD handling precautions must be adhered to at all times to avoid damage to this device.

Table 2. Electrical Specifications: Beam-Lead P-Type Detector Schottky Diodes<sup>1</sup>

	Electrical Characteristics								
Frequency		TSS (dBm) <sup>2</sup>	Rv (Ω)		CJ @ 0 V (pF)	VF@1mA	Test VB @ 10 µA Frequenc		Outline
Band	Part Number	Тур	Min	Max	Max	(mV)	(V)	(GHz)	Drawing
Х	DDB2503-000	-50	500	700	0.15	200-350	2	10.00	491-006
Ku	DDB2504-000	-48	500	700	0.10	200-350	2	16.00	491-006
K	DDB2265-000	-50 <sup>3</sup>	800 <sup>3</sup>	1200 <sup>3</sup>	0.10	300-450	3	24.15	491-006

Performance is guaranteed only under the conditions listed in this table.

Table 3. Electrical Specifications: P-Type Detector Schottky Diode Universal Chips

			Electrical Characteristics						
Frequency			Rv (Ω)	TSS (dBm) <sup>1</sup>	CJ @ 0 V (pF)	VF@1mA	Rτ @ 10 mA (Ω) <sup>2</sup>	VB @ 10 μA (V)	Outline
Band	Part Number	Barrier	Тур	Min	Max	(mV)	Max	Min	Drawing
Ku	CDB7620-000	Low	537	-40	0.15	250-350	30	2	571-006
K	CDB7619-000	Low	735	-50 <sup>3</sup>	0.10	275-375	40	3	571-006

 $<sup>^{1}</sup>$  Bias = 50 μA Video bandwidth = 10 MHz Rv = 2800  $\Omega$ 

<sup>&</sup>lt;sup>2</sup> Bias =  $50 \mu A$ Video bandwidth = 10 MHz.

 $<sup>^3</sup>$  Bias = 30  $\mu$ A

 $<sup>^2</sup>$  Rt is the slope resistance @ 10 mA. The maximum series resistance (Rs) is calculated as: Rs = Rt - 2.8.

 $<sup>^3</sup>$  Bias = 30  $\mu$ A

**Table 4. Electrical Specifications: N-Type Detector Schottky Diode Chips** 

		Electrical Characteristics						
Frequency			VF @ 1 mA	CJ @ 0 V (pF)	Rτ @ 10 mA (Ω)	VB @ 10 μA (V)	Rν (Ω)	Outline
Band	Part Number	Barrier	(mV)	Max	Max	Min	Тур	Drawing
Х	CDF7623-000	Low	240-300	0.30	10	2	245	571-011
K	CDF7621-000	Low	270-350	0.10	20	2	680	571-011
Ku	CME7660-000	Medium	350-450	0.15	10	3	-	571-011
K	CDE7618-000	Medium	375-500	0.10	20	3	_	571-011
Ku	CDP7624-000	Medium/High	450-575	0.15	15	3	-	571-011

**Table 5. SPICE Model Parameters** 

Parameter	Units	Part Number						
		CDB7620-000	CDF7621-000	CDF7623-000	CDB7619-000			
Is	А	4E-08	9E-08	1.1E-07	3E-08			
Rs	Ω	4	6	5	30			
N	-	1.20	1.10	1.10	1.04			
Π	sec	1E-11	1E-11	1E-11	1E-11			
CJO	pF	0.15	0.11	0.20	0.11			
M	-	0.35	0.30	0.30	0.32			
Eg	eV	0.69	0.69	0.69	0.69			
XTI	-	2	2	2	2			
Fc	-	0.5	0.5	0.5	0.5			
Bv	V	2.0	2.5	2.5	3.0			
IBV	А	1E-05	1E-05	1E-05	1E-05			
VJ	V	0.495	0.510	0.510	0.540			

### **Typical I-V Characteristics**

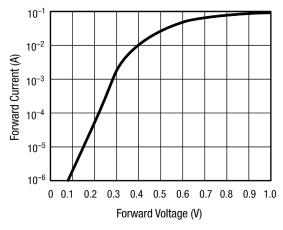


Figure 1. CDF7621-000

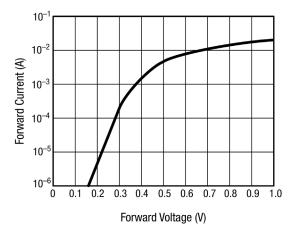


Figure 2. CDB7619-000

## **Typical Performance Data**

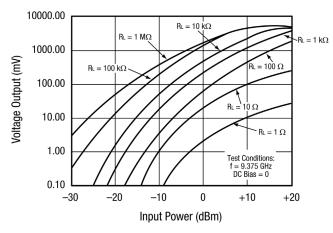


Figure 3. Voltage Output vs Input Power as a Function of Load Resistance

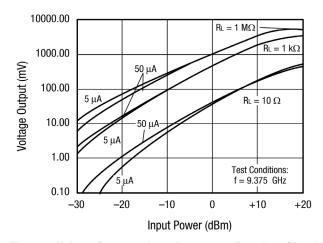
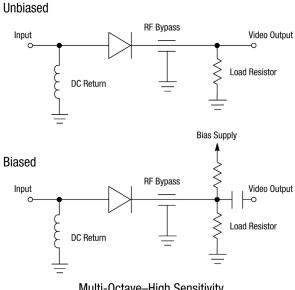
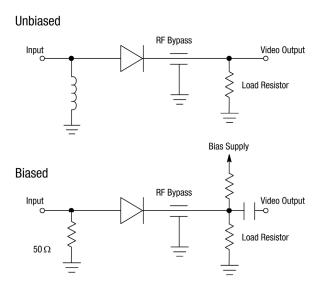


Figure 4. Voltage Output vs Input Power as a Function of Load Resistance and Bias



Multi-Octave-High Sensitivity



Broadband-Low Sensitivity

**Figure 5. Typical Video Detector Circuits** 

## **Shipping Information**

### **Individual Chips**

Skyworks silicon Schottky barrier diodes are provided in waffle packs for bare die and in gel-pack carriers for beamlead devices.

Dimensions are provided in Figures 6, 7, and 8.

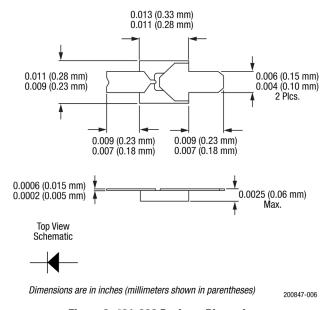


Figure 6. 491-006 Package Dimensions

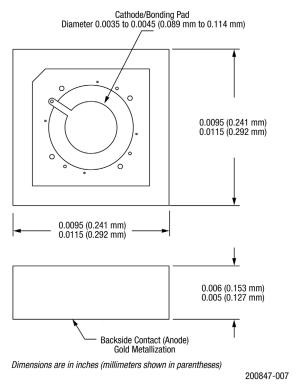


Figure 7. 571-006 Package Dimensions

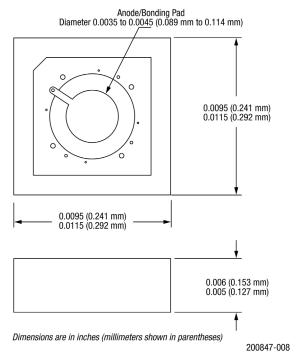


Figure 8. 571-011 Package Dimensions

#### DATA SHEET • SILICON SCHOTTKY BARRIER DIODE BONDABLE CHIPS AND BEAM LEADS

Copyright © 2002-2009, 2011-2014, 2019, 2022 Skyworks Solutions, Inc. All Rights Reserved.

Information in this document is provided in connection with Skyworks Solutions, Inc. ("Skyworks") products or services. These materials, including the information contained herein, are provided by Skyworks as a service to its customers and may be used for informational purposes only by the customer. Skyworks assumes no responsibility for errors or omissions in these materials or the information contained herein. Skyworks may change its documentation, products, services, specifications or product descriptions at any time, without notice. Skyworks makes no commitment to update the materials or information and shall have no responsibility whatsoever for conflicts, incompatibilities, or other difficulties arising from any future changes.

No license, whether express, implied, by estoppel or otherwise, is granted to any intellectual property rights by this document. Skyworks assumes no liability for any materials, products or information provided hereunder, including the sale, distribution, reproduction or use of Skyworks products, information or materials, except as may be provided in Skyworks Terms and Conditions of Sale

THE MATERIALS, PRODUCTS AND INFORMATION ARE PROVIDED "AS IS" WITHOUT WARRANTY OF ANY KIND, WHETHER EXPRESS, IMPLIED, STATUTORY, OR OTHERWISE, INCLUDING FITNESS FOR A PARTICULAR PURPOSE OR USE, MERCHANTABILITY, PERFORMANCE, QUALITY OR NON-INFRINGEMENT OF ANY INTELLECTUAL PROPERTY RIGHT; ALL SUCH WARRANTIES ARE HEREBY EXPRESSLY DISCLAIMED. SKYWORKS DOES NOT WARRANT THE ACCURACY OR COMPLETENESS OF THE INFORMATION, TEXT, GRAPHICS OR OTHER ITEMS CONTAINED WITHIN THESE MATERIALS. SKYWORKS SHALL NOT BE LIABLE FOR ANY DAMAGES, INCLUDING BUT NOT LIMITED TO ANY SPECIAL, INDIRECT, INCIDENTAL, STATUTORY, OR CONSEQUENTIAL DAMAGES, INCLUDING WITHOUT LIMITATION, LOST REVENUES OR LOST PROFITS THAT MAY RESULT FROM THE USE OF THE MATERIALS OR INFORMATION, WHETHER OR NOT THE RECIPIENT OF MATERIALS HAS BEEN ADVISED OF THE POSSIBILITY OF SUCH DAMAGE.

Skyworks products are not intended for use in medical, lifesaving or life-sustaining applications, or other equipment in which the failure of the Skyworks products could lead to personal injury, death, physical or environmental damage. Skyworks customers using or selling Skyworks products for use in such applications do so at their own risk and agree to fully indemnify Skyworks for any damages resulting from such improper use or sale.

Customers are responsible for their products and applications using Skyworks products, which may deviate from published specifications as a result of design defects, errors, or operation of products outside of published parameters or design specifications. Customers should include design and operating safeguards to minimize these and other risks. Skyworks assumes no liability for applications assistance, customer product design, or damage to any equipment resulting from the use of Skyworks products outside of stated published specifications or parameters.

Skyworks, the Skyworks symbol, Sky5®, Sky0ne®, SkyBlue<sup>TM</sup>, Skyworks Green<sup>TM</sup>, Clockbuilder®, DSPLL®, ISOmodem®, ProSLIC®, and SiPHY® are trademarks or registered trademarks of Skyworks Solutions, Inc. or its subsidiaries in the United States and other countries. Third-party brands and names are for identification purposes only and are the property of their respective owners. Additional information, including relevant terms and conditions, posted at www.skyworksinc.com, are incorporated by reference.

# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

# Skyworks:

DDB2265-000 CME7660-000 CDB7620-000 CDE7618-000 CDF7623-000 CDB7619-000 CDF7621-000 DDB2503-000 CDP7624-000 DDB2504-000